



Bipolar PNP Bare Die – BTP6034

Part Description

The BTP6034 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -220V
- VCEO = -200V
- VEBO = -6V
- hFE = 100-300 @ VCE = -5V, IC = -1A
- VCE(Sat) = -0.275V @ IC = -2A, IB = -400mA
- fT = 90 MHz @ VCE = -10V, IE = 0A
- COBO = 32pF @ VCB = -20V

Features

Very Low VCE(sat). Designed to provide performance equivalent to ZETEX / DIODES INC. FZT956

Die Size (Unawn)

1640 μ m X 1640 μ m, 65 Mils X 65 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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